MwT-0307S/Z-LN600
3 – 7 GHz Low Noise Balanced Amplifier Module
May 2015

Features:
- Frequency Range 3 to 7 GHz
- Noise Figure 1.2 dB
- Small Signal Gain 12 dB
- P1dB 16 dBm
- Input/Output RL 15 dB

Description:
The MwT-0307S-LN600 and the MwT-0307Z-LN600 are low noise open-carrier amplifier modules operating between 3 and 7 GHz with excellent broadband noise figure and input and output ports matched to 50 Ω impedance. The substrates for the input and the output matching circuits are ceramic and are mounted on metal carriers. The module can be easily mounted onto the housing of a connectorized amplifier. The noise figure is 1.2 dB across the band. Typical small signal gain is 12 dB. The power output at 1dB compression point is 16 dBm at the mid band. The input and the output VSWR are 1.4:1.

Electrical Specifications: \( V_{ds}=5.0V, \ T_a=25 \degree C, \ Z_0=50 \text{ ohm} \)

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETERS</th>
<th>Unit</th>
<th>Typical Performance</th>
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<tr>
<td>FREQ</td>
<td>Frequency Range</td>
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<td>3 – 7</td>
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<td>SSG</td>
<td>Small Signal Gain</td>
<td>dB</td>
<td>12</td>
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<tr>
<td>GOF</td>
<td>SSG Flatness</td>
<td>+/- dB</td>
<td>0.5</td>
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<tr>
<td>GOT</td>
<td>SSG Variation over Temperature</td>
<td>dB/°C</td>
<td>-0.012</td>
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<tr>
<td>P-1dB</td>
<td>Output Power at 1 dB Compression</td>
<td>dBm</td>
<td>16</td>
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<tr>
<td>NF</td>
<td>Noise Figure</td>
<td>dB</td>
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<td>VSWR</td>
<td>Input/Output VSWR</td>
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<td>1.5:1</td>
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<tr>
<td>VDD</td>
<td>Power Supply Voltage</td>
<td>+V</td>
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<tr>
<td>IDD</td>
<td>Small Signal Module Current</td>
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Typical RF Performance: \( V_{ds}=5.0\text{V}, I_{dd} = 100 \text{ mA}, T_a=25 \text{ °C}, Z_0=50 \text{ ohm} \)
Package Outline:

Construction:
The 15 mil alumina substrates and 10 mil copper FET ridge are brazed onto the 25 mil carrier using AuGe perform. The GaAs FETs are attached to the Cu ridge using AuSn perform. All capacitors are attached using AuSn performs. The flanges are designed to accommodate 0-80 UNF-2A socket or Fillister head screws on .400 center-to-center hole spacing. The modules are mechanically and electrically designed to be cascaded.

Notes:

1. Custom module specifications and/or custom module mechanical configurations are available.
2. Operating Temperature Range is −55 degrees Celsius to +105 degrees Celsius.
3. All modules are serialized and shipped with data measured at 25 degrees Celsius. Data includes swept small signal gain, swept input and output return loss. Noise figure and P1dB are measured in 1 GHz increments. Special module testing is available.
4. Test Fixtures are available.
5. Microwave Technology reserves the right to ship modules with performance above the typical specification.